



Espacenet

Citation origin	Publication	Title	Earliest priority date	Publication date	Applicants	IPC	CPC
SEA	DE102012107472A1	Solar cell for solar panel, has dielectric layer provided with openings through which electrical layer is contacted with backside of silicon substrate, and p-doped back-side selective emitter provided at silicon substrate	2012-08-15	2014-02-20	SOLARWORLD INNOVATIONS GMBH [DE]	H01L31/0216, H01L31/0224, H01L31/068, H01L31/18	H10F10/14 (EP), H10F71/121 (EP), H10F77/211 (EP), H10F77/311 (EP), Y02E10/547 (EP), Y02P70/50 (EP)
SEA	CN104952943A	High-efficiency solar cell structures and methods of manufacture	2009-04-21	2015-09-30	TETRASUN INC	H01L31/0216, H01L31/042, H01L31/18	H10F10/00 (KR), H10F10/165 (EP), H10F19/00 (CN), H10F71/00 (CN,KR), H10F71/128 (EP,CN,KR,US), H10F71/129 (EP,KR,US), H10F71/131 (EP,KR,US), H10F71/138 (KR,US), H10F77/211 (EP,KR,US), H10F77/244 (KR,US), H10F77/30 (KR), H10F77/311 (EP,CN,KR,US), H10F77/315 (KR,US), H10F19/33 (US), Y02E10/50 (KR,US), Y02E10/548 (EP), Y02P70/50 (EP,KR,US)
SEA	CN206864484U	Passivation contact solar cell	2017-07-12	2018-01-09	TAIZHOU ZHONGLAI PHOTOELECTRIC TECH CO LTD	H01L31/0216, H01L31/0224, H01L31/068, H01L31/18	Y02E10/546 (EP), Y02P70/50 (EP)
SEA	CN208315578U	Si base double -faced solar cell structure with local projecting pole characteristic	2018-03-12	2019-01-01	UNIV NANCHANG	H01L31/068	Y02E10/547 (EP)
SEA	CN109256440A	A selective passivation contact crystal silicon solar cell and a preparation method thereof	2018-09-17	2019-01-22	ZHEJIANG AIKO SOLAR ENERGY TECH CO LTD, GUANGDONG AIKO SOLAR ENERGY TECHNOLOGY CO LTD	H01L31/0216, H01L31/068, H01L31/18	H10F10/14 (CN,KR,US), H10F10/165 (EP), H10F71/121 (CN,KR), H10F71/1221 (US), H10F71/129 (CN,KR), H10F77/211 (EP), H10F77/311 (EP,CN,KR), H10F77/315 (EP,US), H10F77/703 (EP), Y02E10/546 (EP,KR), Y02E10/547 (EP,KR), Y02P70/50 (EP,KR)
SEA	CN209104161U	A selective passivation contact solar cell	2018-09-17	2019-07-12	ZHEJIANG AIKO SOLAR ENERGY TECH CO LTD, GUANGDONG AIKO SOLAR ENERGY TECHNOLOGY CO LTD	H01L31/0216, H01L31/068	Y02E10/546 (EP)
SEA	CN110098279A	Method for fabricating solar cell	2018-01-30	2019-08-06	SHANGHAI KINGSTONE SEMICONDUCTOR CORP	H01L31/0224, H01L31/18	H10F71/121 (CN), H10F77/215 (CN), Y02E10/547 (EP), Y02P70/50 (EP)

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SEA	CN110137274A	Double-sided passivation contact P-type high-efficiency battery and preparation method thereof	2019-05-24	2019-08-16	TONGWEI SOLAR HEFEI CO LTD, TONGWEI SOLAR CHENGDU CO LTD	H01L31/0216, H01L31/0224, H01L31/0236, H01L31/028, H01L31/0352, H01L31/18	H10F71/121 (CN), H10F77/122 (CN), H10F77/14 (CN), H10F77/211 (CN), H10F77/315 (CN), H10F77/703 (CN), Y02P70/50 (EP)
SEA	CN110265494A	Local back-field TOPCon solar cell and preparation method thereof	2019-07-12	2019-09-20	JOLYWOOD SUZHOU SUNWATT CO LTD, TAIZHOU ZHONG LAI PHOTOELECTRIC TECH CO LTD	H01L31/0216, H01L31/0224, H01L31/0236, H01L31/0352, H01L31/18	H10F71/137 (CN), H10F77/14 (CN), H10F77/219 (CN), H10F77/315 (CN), H10F77/70 (CN), Y02E10/50 (EP), Y02P70/50 (EP)
SEA	CN105742391A	Tunnel silicon oxide passivated contact solar cell and preparation method thereof	2016-04-27	2016-07-06	NINGBO INST MAT TECH & ENG CAS	H01L31/0216, H01L31/048	H10F19/80 (CN), H10F19/804 (CN), H10F77/30 (CN), H10F77/311 (CN), Y02E10/50 (EP)
SEA	CN106057921A	Micro-nano textured solar cell emitter, solar cell provided with same, and manufacturing method thereof	2016-07-20	2016-10-26	SUZHOU CSI SOLAR POWER TECH CO	H01L31/0224, H01L31/18	H10F71/137 (CN), H10F77/211 (CN), Y02E10/50 (EP), Y02P70/50 (EP)